Ref #	Hits	Search Query	DBs	Default Operato r	Plural s	Time Stamp
L1	18	("6130102" "6245669" "63130 25" "6399512" "6602434" "66 35566" "6734108" "6803318"  "6849193").PN.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:41
L2	1416	Qiao.in.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:41
L3	8	2 and ("C.sub.2" adj "H.sub.2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:44
L4	2	trench adj dielectric and etch adj stop and oxide and ("C. sub.2" adj "H.sub.2" adj "F. sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L5	1218	438/700.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45

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L6	3009	438/714.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45
L7	1107	438/723.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45
L8	625	438/738.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45
L9	357	438/740.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45
L10	1425	438/585.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45

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L11	2772	438/637.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:45
L12	22	5 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L13	9	6 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L14	21	7 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L15	5	8 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46

L16	8	9 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L17	5	10 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L18	70	11 and trench adj dielectric and etch adj stop and oxide	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L19	0	12 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:46
L20	0	13 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47

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L21	1	14 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47
L22	1	15 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47
L23	1	16 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47
L24	0	17 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47
L25	0	18 and ("C.sub.2" adj "H.sub. 2" adj "F.sub.4")	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/11/12 09:47

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